Product data sheet

1. General description

PNP medium power transistors in a SOT223 (SC-73) Surface-Mounted Device (SMD) plastic package.

2. Features and benefits

- High current
- Three current gain selections
- · High power dissipation capability
- AEC-Q101 qualified

3. Applications

- Linear voltage regulators
- · High-side switches
- · Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

4. Quick reference data

Table 1. Quick reference data

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V_{CEO}	collector-emitter voltage	open base		-	-	-45	V	
I _C	collector current			-	-	-1	A	
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	-2	А	
h _{FE}	DC current gain							
	BCP51	V _{CE} = -2 V; I _C = -150 mA	[1]	63	-	250		
	BCP51-10	T _{amb} = 25 °C	[1]	63	-	160		
	BCP51-16		[1]	100	-	250		

[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$



45 V, 1 A PNP medium power transistors

5. Pinning information

Table 2. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	C
2	С	collector		, , , , , , , , , , , , , , , , , , ,
3	E	emitter		
4	С	collector	□ 1 □ 2 □ 3	Ė
				sym028

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BCP51	-	plastic, surface-mounted package with increased heatsink;	<u>SOT223</u>			
BCP51-10		4 leads; 2.3 mm pitch; 6.5 mm x 3.5 mm x 1.65 mm body				
BCP51-16						

7. Marking

Table 4. Marking

Type number	Marking code
BCP51	BCP51
BCP51-10	BCP51/10
BCP51-16	BCP51/16

45 V, 1 A PNP medium power transistors

8. Limiting values

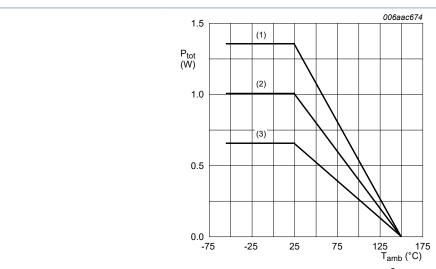
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

 T_{amb} = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	open emitter		-45	V
V _{CEO}	collector-emitter voltage	open base		-	-45	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current			-	-1	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		-2	Α
I _B	base current			-	-0.3	Α
I _{BM}	peak base current	single pulse; t _p ≤ 1 ms	single pulse; t _p ≤ 1 ms		-0.3	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	0.65	W
			[2]	-	1.00	W
			[3]	-	1.35	W
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C

- Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.
- Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm². Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm².



- (1) FR4 PCB, single-sided copper, mounting pad for collector 6 cm²
- (2) FR4 PCB, single-sided copper, mounting pad for collector 1 cm²
- (3) FR4 PCB, single-sided copper, standard footprint

Fig. 1. Power derating curves

45 V, 1 A PNP medium power transistors

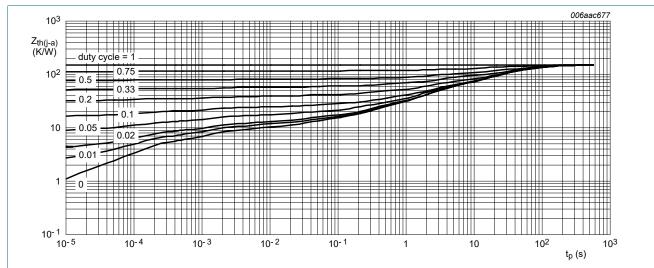
9. Thermal characteristics

Table 6. Thermal characteristics

 T_{amb} = 25 °C unless otherwise specified.

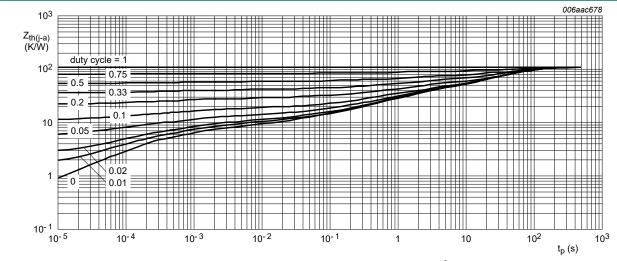
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	192	K/W
			[2]	-	-	125	K/W
			[3]	-	-	93	K/W
R _(j-sp)	thermal resistance from junction to solder point			-	-	16	K/W

- [1] Device mounted on an FR4 PCB; single-sided copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²
- [3] Device mounted on an FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 6 cm².



FR4 PCB; single-sided copper; tin-plated and standard footprint

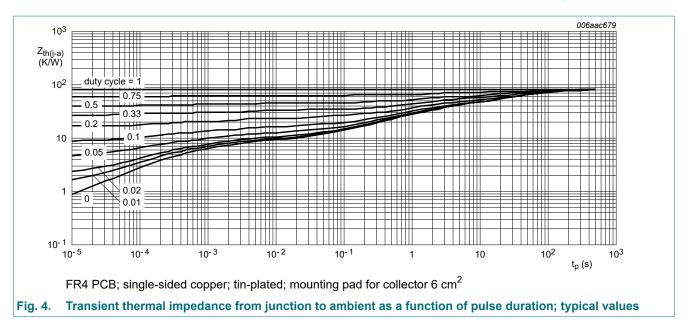
Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB; single-sided copper; tin-plated; mounting pad for collector 1 cm²

Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

45 V, 1 A PNP medium power transistors



45 V, 1 A PNP medium power transistors

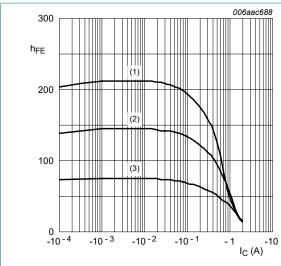
10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
I _{CBO}	collector-base cut-off current	V _{CB} = -30 V; I _E = 0 A T _{amb} = 25 °C		-	-	-100	nA		
		V _{CB} = -30 V; I _E = 0 A; T _j = 150 °C		-	-	-10	μΑ		
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A T _{amb} = 25 °C		-	-	-100	nA		
h _{FE}	DC current gain								
	BCP51	V _{CE} = -2 V; I _C = -5 mA T _{amb} = 25 °C	[1]	63	-	-			
		V _{CE} = -2 V; I _C = -150 mA T _{amb} = 25 °C		63	-	250			
		V _{CE} = -2 V; I _C = -500 mA T _{amb} = 25 °C		40	-	-			
	BCP51-10	V _{CE} = -2 V; I _C = -5 mA T _{amb} = 25 °C	[1]	63	-	-			
		V _{CE} = -2 V; I _C = -150 mA T _{amb} = 25 °C		63	-	160			
		V _{CE} = -2 V; I _C = -500 mA T _{amb} = 25 °C		40	-	-			
	BCP51-16	V _{CE} = -2 V; I _C = -5 mA T _{amb} = 25 °C	[1]	63	-	-			
		V _{CE} = -2 V; I _C = -150 mA T _{amb} = 25 °C		100	-	250			
		V _{CE} = -2 V; I _C = -500 mA T _{amb} = 25 °C		40	-	-			
V _{CEsat}	collector-emitter saturation voltage	I_C = -500 mA; I_B = -50 mA T_{amb} = 25 °C	[1]	-	-	-0.5	V		
V_{BE}	base-emitter voltage	V _{CE} = -2 V; I _C = -500 mA T _{amb} = 25 °C	[1]	-	-	-1	V		
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = i_{e} = 0 A; f = 1 MHz T_{amb} = 25 °C		-	15	-	pF		
f _T	transition frequency	V _{CE} = -5 V; I _C = -50 mA; f = 100 MHz T _{amb} = 25 °C		-	145	-	MHz		

^[1] pulsed; $t_p \le 300 \ \mu s; \ \delta \le 0.02$

45 V, 1 A PNP medium power transistors



$$V_{CE} = -2 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 5. DC current gain as a function of collector current; typical values

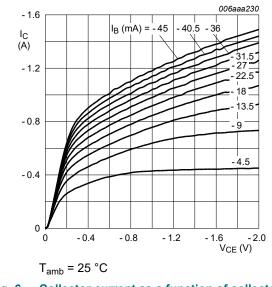
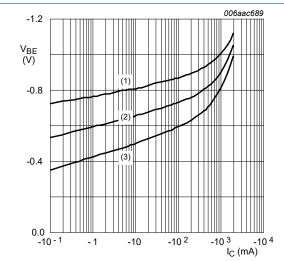


Fig. 6. Collector current as a function of collectoremitter voltage; typical values



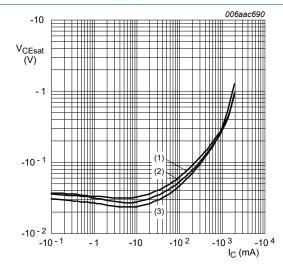
$$V_{CE} = -2 V$$

(1)
$$T_{amb} = -55 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb}$$
 = 100 °C

Fig. 7. Base-emitter voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(3)
$$T_{amb} = -55 \, ^{\circ}C$$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

7/12

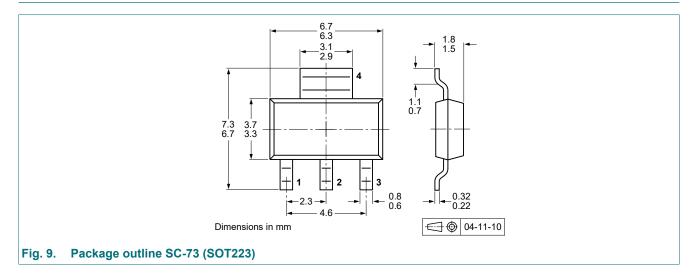
45 V, 1 A PNP medium power transistors

11. Test information

11.1. Quality information

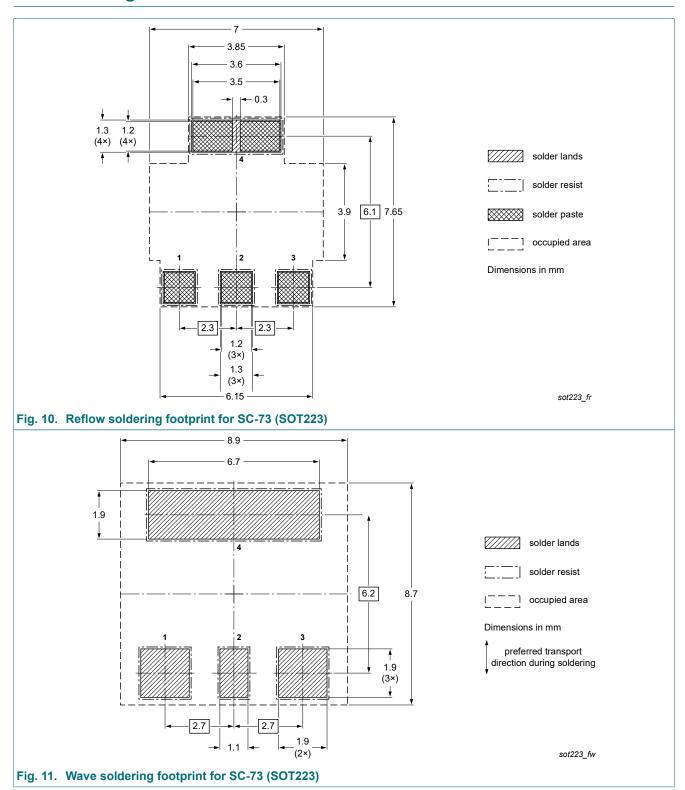
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



45 V, 1 A PNP medium power transistors

13. Soldering



45 V, 1 A PNP medium power transistors

14. Revision history

Table 8. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes
BCP51_SER v.10	20231016	Product data sheet	-	BCP51_BCX51_BC51PA v.9
Modifications:	Data sheet sepaSection "Packing"			
BCP51_BCX51_BC51PA v.9	20111013	Product data sheet	-	BC636_BCP51_BCX51 v.8
BC636_BCP51_BCX51 v.8	20080222	Product data sheet	-	BC636_BCP51_BCX51 v.7
BC636_BCP51_BCX51 v.7	20070629	Product data sheet	-	BC636_BCP51_BCX51 v.6
BC636_BCP51_BCX51 v.6	20060329	Product data sheet	-	BC636_638_640 v.5 BCP51_52_53 v.5 BCX51_52_53 v.4
BC636_638_640 v.5	20041011	Product specification	-	BCX51_52_53 v.5
BCX51_52_53 v.5	20030206	Product specification	-	BCX51_52_53 v.4
BCX51_52_53 v.4	20011010	Product specification	-	BCX51_52_53 v.3

45 V, 1 A PNP medium power transistors

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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BCP51_SER

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45 V, 1 A PNP medium power transistors

Contents

1
1
1
1
2
2
2
3
4
6
8
8
8
9
10
11

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